

CURRENT SHUNT MONITORS

–16 V to +80 V Common Mode Range

FEATURES

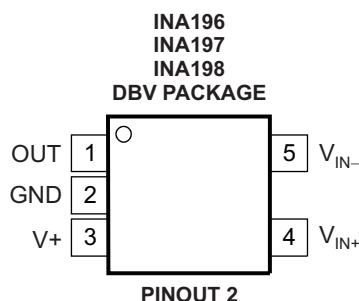
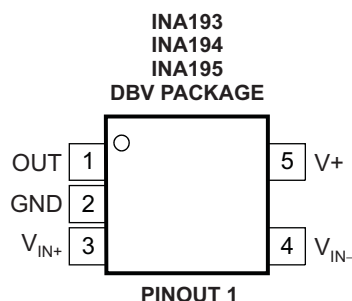
- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of –55°C to 125°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree ⁽¹⁾**
- **Wide Common-Mode Voltage: –16 V to +80 V**
- **Low Error: 3.0% Over Temp (Max)**
- **Bandwidth: Up to 500 kHz**
- **Three Transfer Functions Available: 20 V/V, 50 V/V, and 100 V/V**

(1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- **Complete Current Sense Solution**

APPLICATIONS

- **Welding Equipment**
- **Notebook Computers**
- **Cell Phones**
- **Telecom Equipment**
- **Automotive**
- **Power Management**
- **Battery Chargers**



DESCRIPTION

The INA193A–INA198A family of current shunt monitors with voltage output can sense drops across shunts at common-mode voltages from –16 V to 80 V, independent of the INA19x supply voltage. They are available with three output voltage scales: 20 V/V, 50 V/V, and 100 V/V. The 500 kHz bandwidth simplifies use in current control loops. The INA193A–INA195A provide identical functions but alternative pin configurations to the INA196A–INA198A, respectively.

The INA193A–INA198A operate from a single 2.7 V to 18 V supply, drawing a maximum of 1300 μ A of supply current. They are specified over the extended operating temperature range (–55°C to 125°C), and are offered in a space-saving SOT23 package.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION

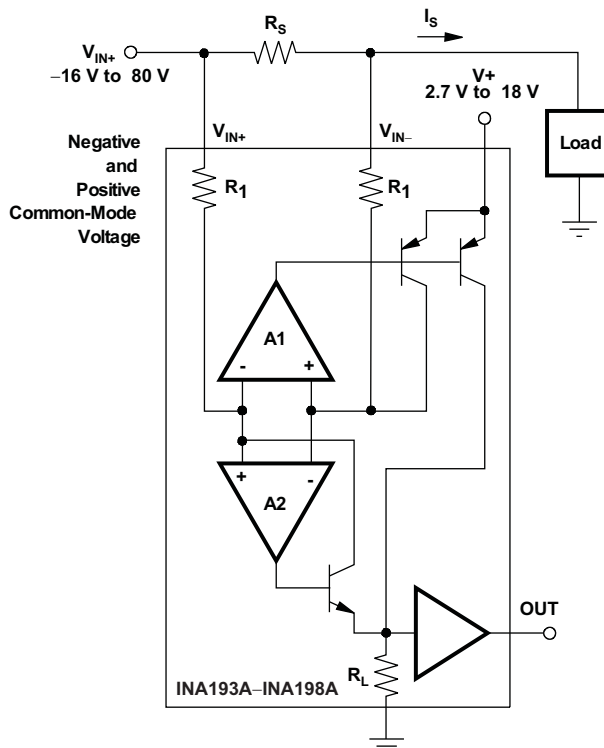
T_A	PACKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C	SOT23-5 – DBV	INA193AMDBVREP	CCC
		INA194AMDBVREP ⁽²⁾	TBD
		INA195AMDBVREP ⁽²⁾	TBD
		INA196AMDBVREP ⁽²⁾	TBD
		INA197AMDBVREP ⁽²⁾	TBD
		INA198AMDBVREP ⁽²⁾	TBD

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) Product Preview

MODEL	GAIN	PACKAGE	PINOUT ⁽¹⁾
INA193A	20 V/V	SOT23-5	Pinout 1
INA194A	50 V/V	SOT23-5	Pinout 1
INA195A	100 V/V	SOT23-5	Pinout 1
INA196A	20 V/V	SOT23-5	Pinout 2
INA197A	50 V/V	SOT23-5	Pinout 2
INA198A	100 V/V	SOT23-5	Pinout 2

(1) See pin assignments for pinout 1 and pinout 2



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
Supply voltage			18		V
V _{IN+} V _{IN-}	Analog input voltage range	Differential (V _{IN+} – V _{IN-})	–18	18	V
		Common mode ⁽²⁾	–16	80	
Analog outputt voltage range ⁽²⁾		OUT	GND – 0.3	(V+) + 0.3	V
Input current into any pin ⁽²⁾			5		mA
Operating temperature range			–55	150	°C
Storage temperature range			–65	150	°C
Junction temperature			150		°C
ESD ratings	Human-Body Model (HBM)		4000		V
	Charged-Device Model (CDM)		1000		

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Input voltage at any pin may exceed the voltage shown if the current at that pin is limited to 5 mA.

Electrical Characteristics

$V_S = +12$ V. **Boldface** limits apply over the specified temperature range, $T_A = -55^\circ\text{C}$ to 125°C . All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12$ V, $V_{IN+} = 12$ V, and $V_{SENSE} = 100$ mV (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT					
Full-scale input voltage	$V_{SENSE} = V_{IN+} - V_{IN-}$		0.15	$(V_S - 0.2)/\text{Gain}$	V
Common-mode input range	V_{CM}	–16		80	V
Common-mode rejection	CMR	80	94		dB
Over temperature	$V_{IN+} = -16$ V to 80 V $V_{IN+} = 12$ V to 80 V	100	120		dB
Offset voltage, RTI	V_{OS}		± 0.5	2	mV
Over temperature			0.5	3	mV
vs temperature	dV_{OS}/dT		2.5		$\mu\text{V}/^\circ\text{C}$
vs power supply	PSR		5	100	$\mu\text{V}/\text{V}$
Input bias current, V_{IN-} pin	I_B		± 8	± 23	μA
OUTPUT ($V_{SENSE} \geq 20$ mV)					
Gain:	G		20 50 100		V/V V/V V/V
Gain error	$V_{SENSE} = 20$ mV to 100 mV, $T_A = 25^\circ\text{C}$		± 0.2	± 1	%
Over temperature	$V_{SENSE} = 20$ mV to 100 mV			± 2	%
Total output error ⁽¹⁾			± 0.75	± 2.2	%
Over temperature			± 1	± 3	%
Nonlinearity error	$V_{SENSE} = 20$ mV to 100 mV		± 0.002	± 0.1	%
Output impedance	R_O		1.5		Ω
Maximum capacitive load	No sustained oscillation		10		nF

(1) Total output error includes effects of gain error and V_{OS} .

Electrical Characteristics (continued)

$V_S = +12\text{ V}$. **Boldface** limits apply over the specified temperature range, $T_A = -55^\circ\text{C}$ to 125°C . All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$ (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT ($V_{SENSE} < 20\text{ mV}$)⁽²⁾					
All devices	$-16\text{ V} \leq V_{CM} < 0\text{ V}$		300		mV
INA193A, INA196A	$0\text{ V} \leq V_{CM} \leq V_S$, $V_S = 5\text{ V}$			0.4	V
INA194A, INA197A	$0\text{ V} \leq V_{CM} \leq V_S$, $V_S = 5\text{ V}$			1	V
INA195A, INA198A	$0\text{ V} \leq V_{CM} \leq V_S$, $V_S = 5\text{ V}$			2	V
All devices	$V_S < V_{CM} \leq 80\text{ V}$		300		mV
VOLTAGE OUTPUT⁽³⁾					
Swing to V+ power-supply rail	$R_L = 100\text{ K}\Omega$ to GND		(V+) – 0.1	(V+) – 0.2	V
Swing to GND ⁽⁴⁾			$V_{GND} + 3$	$V_{GND} + 50$	mV
FREQUENCY RESPONSE					
Bandwidth	INA193A, INA196A, BW	$C_{LOAD} = 5\text{ pF}$	500		kHz
	INA194A, INA197A,	$C_{LOAD} = 5\text{ pF}$	300		kHz
	INA195A, INA198A	$C_{LOAD} = 5\text{ pF}$	200		kHz
Phase margin		$C_{LOAD} < 10\text{ nF}$	40		Degrees
Slew rate	SR		1		V/ μs
Settling time (1%)	t_S	$V_{SENSE} = 10\text{ mV}$ to 100 mV_{PP} , $C_{LOAD} = 5\text{ pF}$	2		μs
NOISE, RTI					
Voltage noise density			40		nV/ $\sqrt{\text{Hz}}$
POWER SUPPLY					
Operating range	V_S	2.7		18	V
Quiescent Current	I_Q		700	1300	μA
			370	950	μA
TEMPERATURE RANGE					
Specified temperature range		–55		125	$^\circ\text{C}$
Operating temperature range		–55		150	$^\circ\text{C}$
Storage temperature range		–65		150	$^\circ\text{C}$
Thermal resistance, SOT23	θ_{JA}		200		$^\circ\text{C/W}$

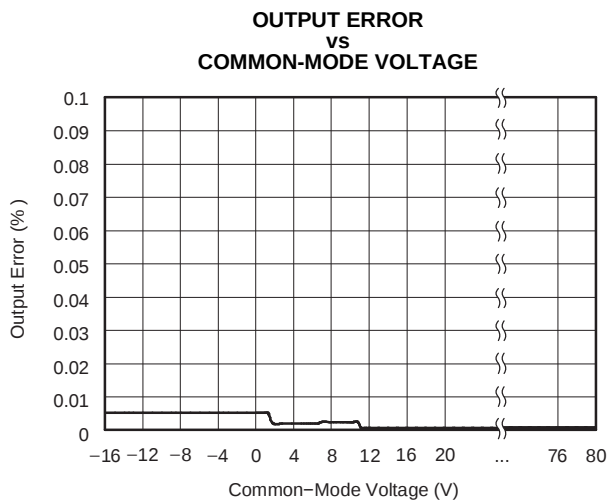
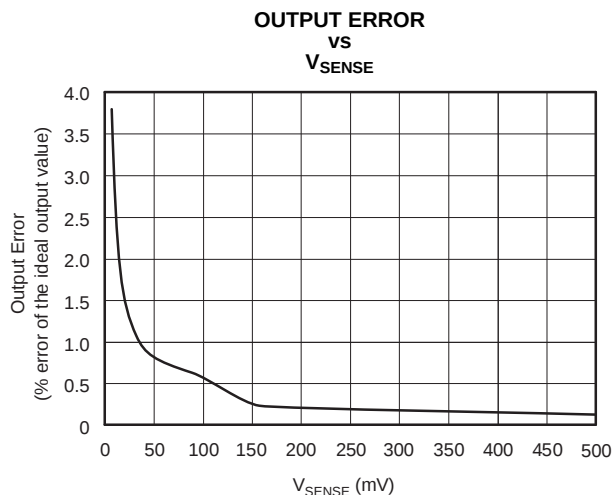
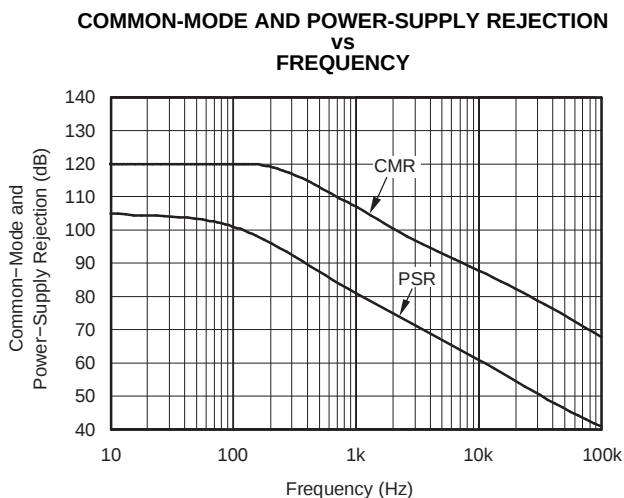
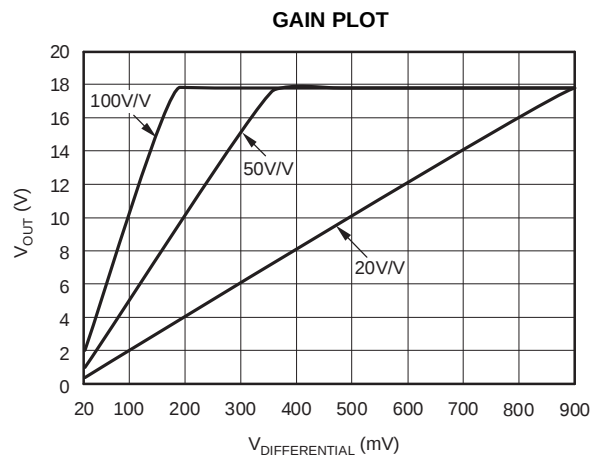
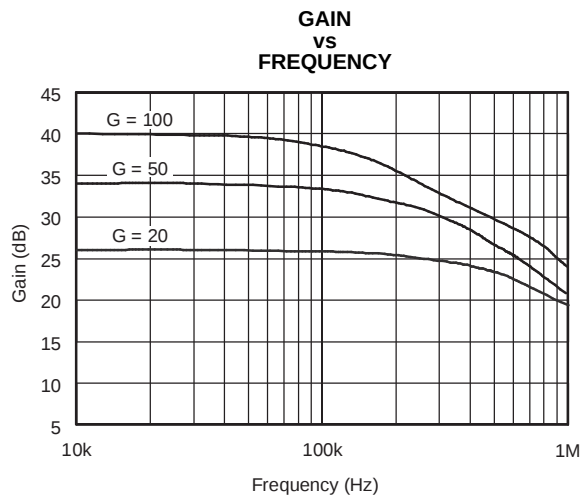
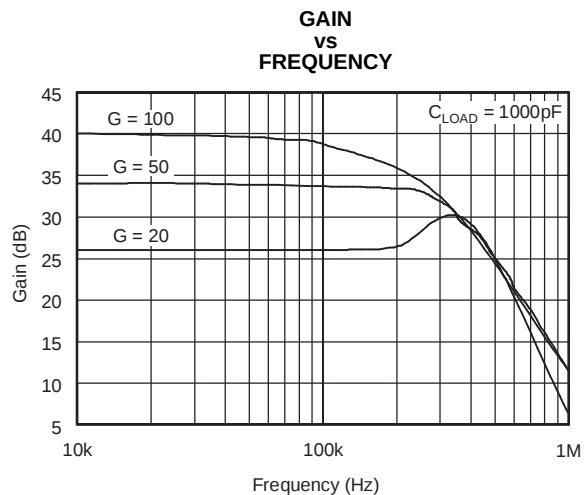
(2) For details on this region of operation, see the *Accuracy Variations as a Result of V_{SENSE} and Common-Mode Voltage* section in the Applications Information.

(3) See Typical Characteristic curve *Output Swing vs Output Current*.

(4) Specified by design

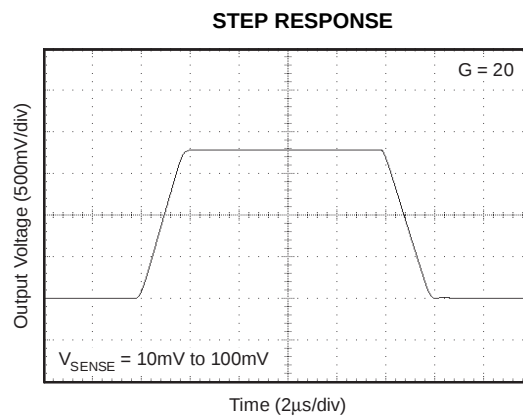
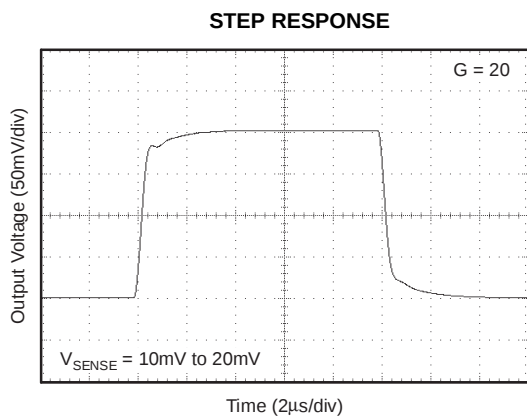
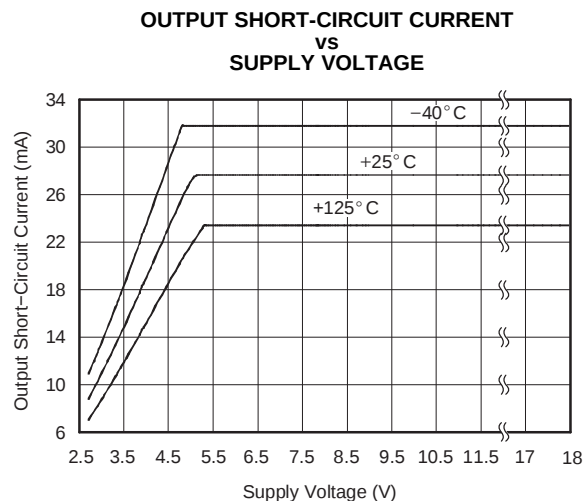
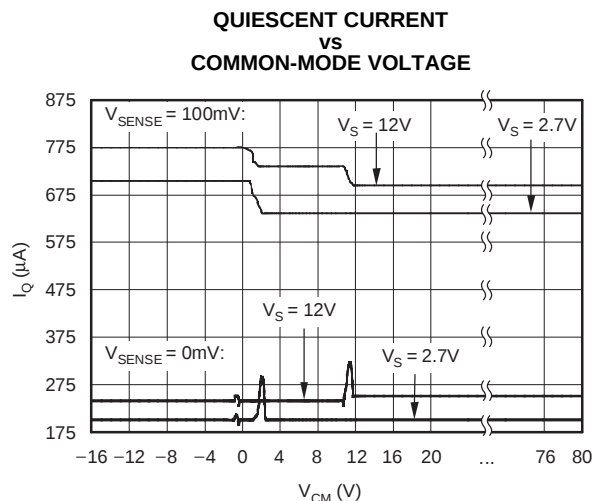
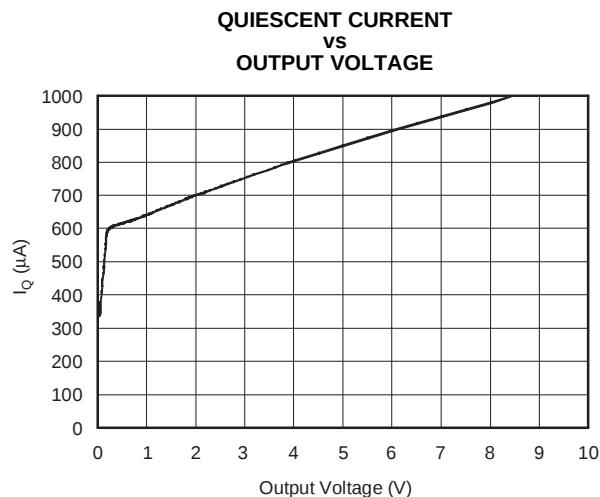
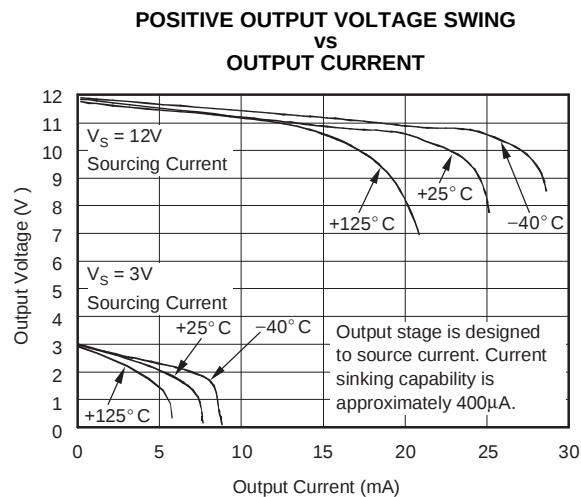
TYPICAL CHARACTERISTICS

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$ (unless otherwise noted).



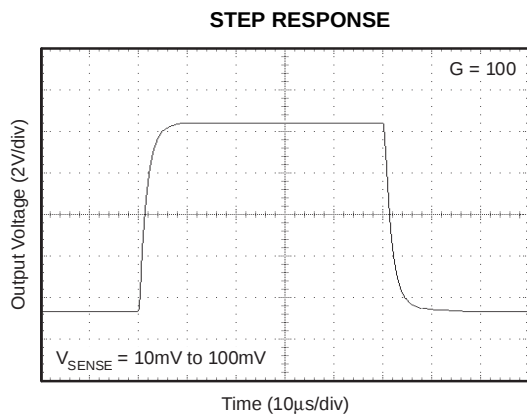
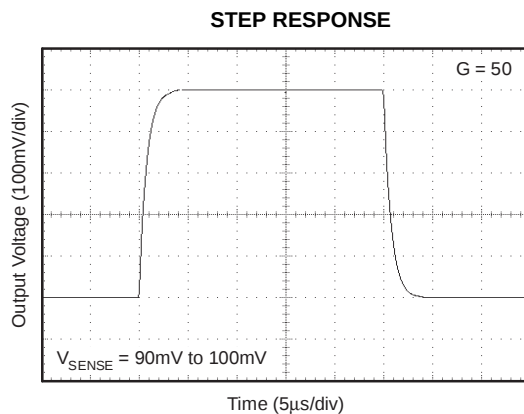
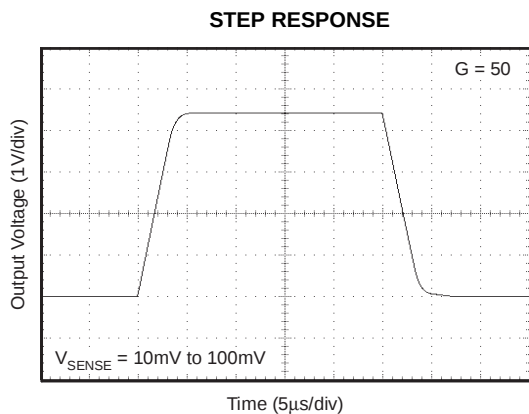
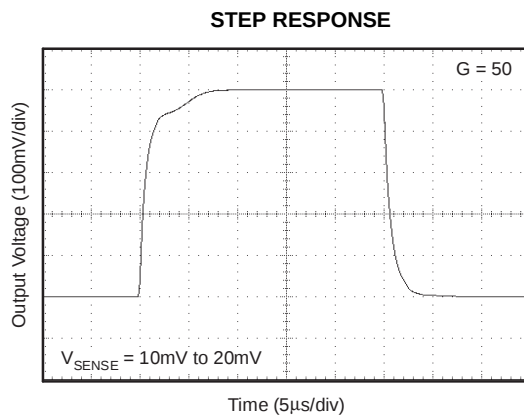
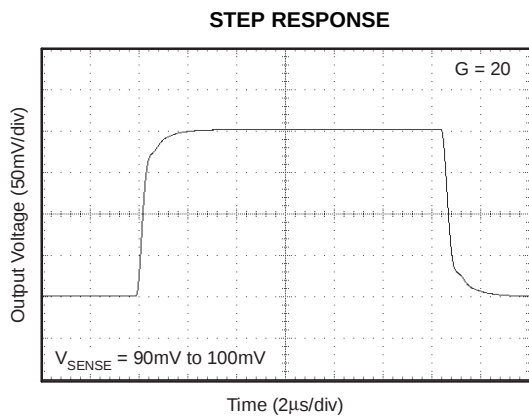
TYPICAL CHARACTERISTICS (continued)

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$ (unless otherwise noted).



TYPICAL CHARACTERISTICS (continued)

All specifications at $T_A = 25^\circ\text{C}$, $V_S = 12\text{ V}$, and $V_{IN+} = 12\text{ V}$, and $V_{SENSE} = 100\text{ mV}$ (unless otherwise noted).



APPLICATION INFORMATION

Basic Connection

Figure 1 shows the basic connection of the INA193A–INA198A. The input pins, V_{IN+} and V_{IN-} , should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

Power-supply bypass capacitors are required for stability. Applications with noisy or high impedance power supplies may require additional decoupling capacitors to reject power supply noise. Connect bypass capacitors close to the device pins.

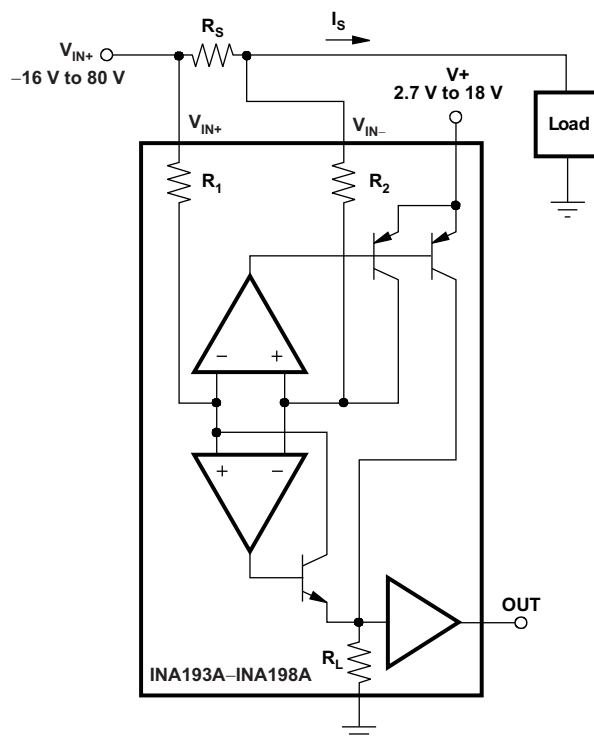


Figure 1. INA193A–INA198A Basic Connection

Power Supply

The input circuitry of the INA193A–INA198A can accurately measure beyond its power supply voltage, $V+$. For example, the $V+$ power supply can be 5 V, whereas the load power supply voltage is up to 80 V. The output voltage range of the OUT terminal, however, is limited by the voltages on the power-supply pin.

Accuracy Variations as a Result of V_{SENSE} and Common-Mode Voltage

The accuracy of the INA193A–INA198A current shunt monitors is a function of two main variables: V_{SENSE} ($V_{IN+} - V_{IN-}$) and common-mode voltage, V_{CM} , relative to the supply voltage, V_S . V_{CM} is expressed as $(V_{IN+} + V_{IN-})/2$; however, in practice, V_{CM} is seen as the voltage at V_{IN+} because the voltage drop across V_{SENSE} is usually small.

APPLICATION INFORMATION (continued)

This section addresses the accuracy of these specific operating regions:

- Normal Case 1: $V_{\text{SENSE}} \geq 20 \text{ mV}$, $V_{\text{CM}} \geq V_{\text{S}}$
 Normal Case 2: $V_{\text{SENSE}} \geq 20 \text{ mV}$, $V_{\text{CM}} < V_{\text{S}}$
 Low V_{SENSE} Case 1: $V_{\text{SENSE}} < 20 \text{ mV}$, $-16 \text{ V} \leq V_{\text{CM}} < 0$
 Low V_{SENSE} Case 2: $V_{\text{SENSE}} < 20 \text{ mV}$, $0 \text{ V} \leq V_{\text{CM}} \leq V_{\text{S}}$
 Low V_{SENSE} Case 3: $V_{\text{SENSE}} < 20 \text{ mV}$, $V_{\text{S}} < V_{\text{CM}} \leq 80 \text{ V}$

Normal Case 1: $V_{\text{SENSE}} \geq 20 \text{ mV}$, $V_{\text{CM}} \geq V_{\text{S}}$

This region of operation provides the highest accuracy. Here, the input offset voltage is characterized and measured using a two-step method. First, the gain is determined by (Equation 1).

$$G = \frac{V_{\text{OUT1}} - V_{\text{OUT2}}}{100 \text{ mV} - 20 \text{ mV}} \quad (1)$$

Where:

V_{OUT1} = Output voltage with $V_{\text{SENSE}} = 100 \text{ mV}$

V_{OUT2} = Output voltage with $V_{\text{SENSE}} = 20 \text{ mV}$

The offset voltage is then measured at $V_{\text{SENSE}} = 100 \text{ mV}$ and referred to the input (RTI) of the current shunt monitor, as shown in (Equation 2).

$$V_{\text{OSRTI}} (\text{Referred-To-Input}) = \left(\frac{V_{\text{OUT1}}}{G} \right) - 100 \text{ mV} \quad (2)$$

In the Typical Characteristics, the *Output Error vs Common-Mode Voltage* curve shows the highest accuracy for the this region of operation. In this plot, $V_{\text{S}} = 12 \text{ V}$; for $V_{\text{CM}} \geq 12 \text{ V}$, the output error is at its minimum. This case is also used to create the $V_{\text{SENSE}} \geq 20 \text{ mV}$ output specifications in the Electrical Characteristics table.

Normal Case 2: $V_{\text{SENSE}} \geq 20 \text{ mV}$, $V_{\text{CM}} < V_{\text{S}}$

This region of operation has slightly less accuracy than Normal Case 1 as a result of the common-mode operating area in which the part functions, as seen in the *Output Error vs Common-Mode Voltage* curve. As noted, for this graph $V_{\text{S}} = 12 \text{ V}$; for $V_{\text{CM}} < 12 \text{ V}$, the Output Error increases as V_{CM} becomes less than 12 V , with a typical maximum error of 0.005% at the most negative $V_{\text{CM}} = -16 \text{ V}$.

Low V_{SENSE} Case 1: $V_{\text{SENSE}} < 20 \text{ mV}$, $-16 \text{ V} \leq V_{\text{CM}} < 0$; and Low V_{SENSE} Case 3: $V_{\text{SENSE}} < 20 \text{ mV}$, $V_{\text{S}} < V_{\text{CM}} \leq 80 \text{ V}$

Although the INA193A–INA198A family of devices are not designed for accurate operation in either of these regions, some applications are exposed to these conditions; for example, when monitoring power supplies that are switched on and off while V_{S} is still applied to the INA193A–INA198A. It is important to know what the behavior of the devices will be in these regions.

As V_{SENSE} approaches 0 mV, in these V_{CM} regions, the device output accuracy degrades. A larger-than-normal offset can appear at the current shunt monitor output with a typical maximum value of $V_{\text{OUT}} = 300 \text{ mV}$ for $V_{\text{SENSE}} = 0 \text{ mV}$. As V_{SENSE} approaches 20 mV, V_{OUT} returns to the expected output value with accuracy as specified in the Electrical Characteristics. Figure 2 illustrates this effect using the INA195A and INA198A (Gain = 100).

APPLICATION INFORMATION (continued)

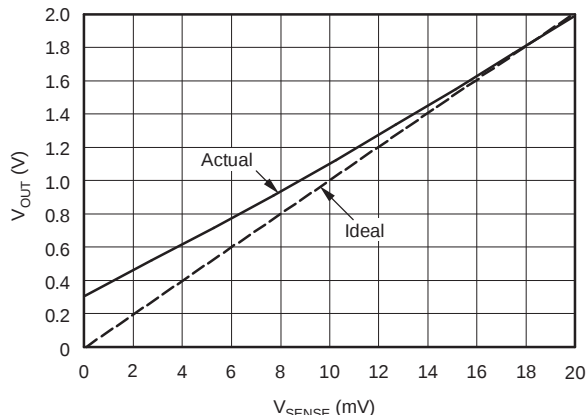
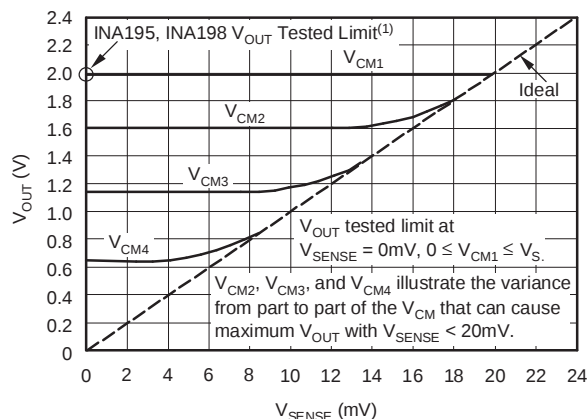


Figure 2. Example for Low V_{SENSE} Cases 1 and 3 (INA195A, INA198A: Gain = 100)

Low V_{SENSE} Case 2: $V_{SENSE} < 20$ mV, 0 V $\leq V_{CM} \leq V_S$

This region of operation is the least accurate for the INA193A–INA198A family. To achieve the wide input common-mode voltage range, these devices use two op amp front ends in parallel. One op amp front end operates in the positive input common-mode voltage range, and the other in the negative input region. For this case, neither of these two internal amplifiers dominates and overall loop gain is very low. Within this region, V_{OUT} approaches voltages close to linear operation levels for Normal Case 2. This deviation from linear operation becomes greatest the closer V_{SENSE} approaches 0 V. Within this region, as V_{SENSE} approaches 20 mV, device operation is closer to that described by Normal Case 2. Figure 3 illustrates this behavior for the INA195A. The V_{OUT} maximum peak for this case is tested by maintaining a constant V_S , setting $V_{SENSE} = 0$ mV and sweeping V_{CM} from 0 V to V_S . The exact V_{CM} at which V_{OUT} peaks during this test varies from part to part, but the V_{OUT} maximum peak is tested to be less than the specified V_{OUT} tested limit.



NOTE: (1) INA193, INA196 V_{OUT} Tested Limit = 0.4V.
INA194, INA197 V_{OUT} Tested Limit = 1V.

Figure 3. Example for Low V_{SENSE} Case 2 (INA195A, INA198A: Gain = 100)

APPLICATION INFORMATION (continued)

Shutdown

Because the INA193A–INA198A consume a quiescent current less than 1 mA, they can be powered by either the output of logic gates or by transistor switches to supply power. Use a totem pole output buffer or gate that can provide sufficient drive along with 0.1 μF bypass capacitor, preferably ceramic with good high frequency characteristics. This gate should have a supply voltage of 3 V or greater because the INA193A–INA198A requires a minimum supply greater than 2.7 V. In addition to eliminating quiescent current, this gate also turns off the 10 μA bias current present at each of the inputs. An example shutdown circuit is shown in [Figure 4](#).

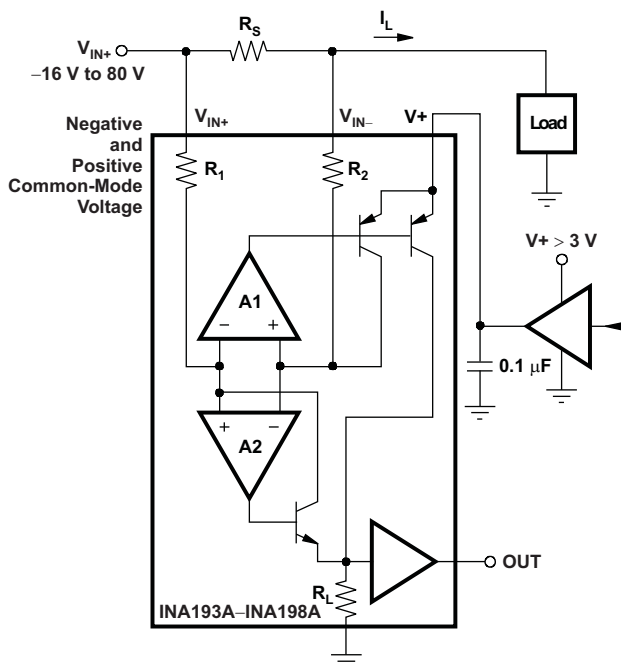


Figure 4. INA193A–INA198A Example Shutdown Circuit

Selecting R_S

The value chosen for the shunt resistor, R_S , depends on the application and is a compromise between small-signal accuracy and maximum permissible voltage loss in the measurement line. High values of R_S provide better accuracy at lower currents by minimizing the effects of offset, while low values of R_S minimize voltage loss in the supply line. For most applications, best performance is attained with an R_S value that provides a full-scale shunt voltage range of 50 mV to 100 mV. Maximum input voltage for accurate measurements is 500 mV.

Transient Protection

The –16 V to 80 V common-mode range of the INA193A–INA198A is ideal for withstanding automotive fault conditions ranging from 12 V battery reversal up to 80 V transients, since no additional protective components are needed up to those levels. In the event that the INA193A–INA198A is exposed to transients on the inputs in excess of its ratings, then external transient absorption with semiconductor transient absorbers (zeners or Transzorbs) will be necessary. Use of MOVs or VDRs is not recommended except when they are used in addition to a semiconductor transient absorber. Select the transient absorber such that it will never allow the INA193A–INA198A to be exposed to transients greater than 80 V (that is, allow for transient absorber tolerance, as well as additional voltage due to transient absorber dynamic impedance). Despite the use of internal zener type ESD protection, the INA193A–INA198A does not lend itself to using external resistors in series with the inputs since the internal gain resistors can vary up to $\pm 30\%$. (If gain accuracy is not important, then resistors can be added in series with the INA193A–INA198A inputs with two equal resistors on each input.)

APPLICATION INFORMATION (continued)

Output Voltage Range

The output of the INA193A–INA198A is accurate within the output voltage swing range set by the power-supply pin, V+. This is best illustrated when using the INA195A or INA198A (which are both versions using a gain of 100), where a 100 mV full-scale input from the shunt resistor requires an output voltage swing of 10 V, and a power-supply voltage sufficient to achieve 10 V on the output.

RFI/EMI

Attention to good layout practices is always recommended. Keep traces short and, when possible, use a printed circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Small ceramic capacitors placed directly across amplifier inputs can reduce RFI/EMI sensitivity. PCB layout should locate the amplifier as far away as possible from RFI sources. Sources can include other components in the same system as the amplifier itself, such as inductors (particularly switched inductors handling a lot of current and at high frequencies). RFI can generally be identified as a variation in offset voltage or dc signal levels with changes in the interfering RF signal. If the amplifier cannot be located away from sources of radiation, shielding may be needed. Twisting wire input leads makes them more resistant to RF fields. The difference in input pin location of the INA193A–INA195A versus the INA196A–INA198A may provide different EMI performance.

Input Filtering

An obvious and straightforward location for filtering is at the output of the INA193A–INA198A; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA193A–INA198A, which is complicated by the internal 5 kΩ + 30% input impedance; this is illustrated in [Figure 5](#). Using the lowest possible resistor values minimizes both the initial shift in gain and effects of tolerance. The effect on initial gain is given by:

$$\text{GainError\%} = 100 - \left(100 \times \frac{5\text{ k}\Omega}{5\text{ k}\Omega + R_{\text{FILT}}} \right) \quad (3)$$

Total effect on gain error can be calculated by replacing the 5-kΩ term with 5 kΩ – 30%, (or 3.5 kΩ) or 5 kΩ + 30% (or 6.5 kΩ). The tolerance extremes of R_{FILT} can also be inserted into the equation. If a pair of 100-Ω 1% resistors are used on the inputs, the initial gain error will be approximately 2%. Worst-case tolerance conditions will always occur at the lower excursion of the internal 5 kΩ resistor (3.5 kΩ), and the higher excursion of R_{FILT} – 3% in this case. Note that the specified accuracy of the INA193A–INA198A must then be combined in addition to these tolerances. While this discussion treated accuracy worst-case conditions by combining the extremes of the resistor values, it is appropriate to use geometric mean or root sum square calculations to total the effects of accuracy variations.

APPLICATION INFORMATION (continued)

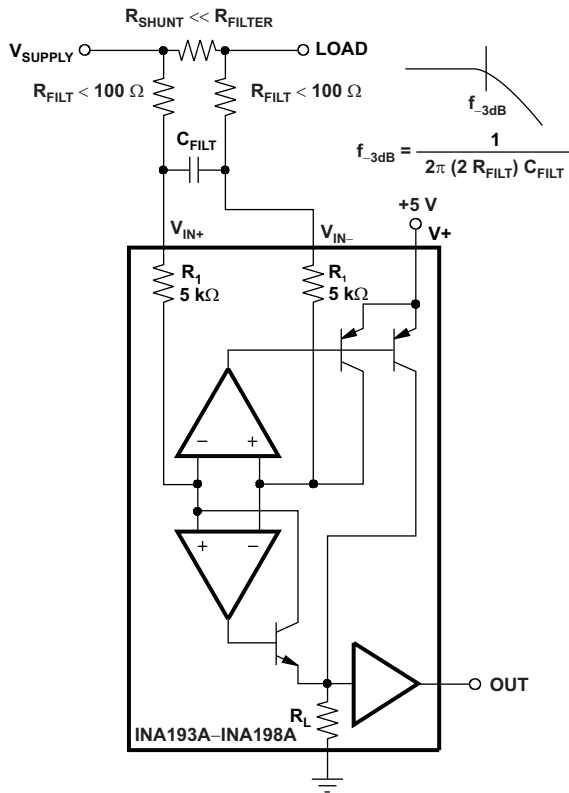


Figure 5. Input Filter (Gain Error – 15% to –2.2%)

Inside the INA193A–INA198A

The INA193A–INA198A uses a new, unique internal circuit topology that provides common-mode range extending from –16 V to 80 V while operating from a single power supply. The common-mode rejection in a classic instrumentation amp approach is limited by the requirement for accurate resistor matching. By converting the induced input voltage to a current, the INA193A–INA198A provides common-mode rejection that is no longer a function of closely matched resistor values, providing the enhanced performance necessary for such a wide common-mode range. A simplified diagram (shown in [Figure 6](#)) shows the basic circuit function. When the common-mode voltage is positive, amplifier A2 is active.

The differential input voltage, $(V_{IN+}) - (V_{IN-})$ applied across R_S , is converted to a current through a resistor. This current is converted back to a voltage through R_L , and then amplified by the output buffer amplifier. When the common-mode voltage is negative, amplifier A1 is active. The differential input voltage, $(V_{IN+}) - (V_{IN-})$ applied across R_S , is converted to a current through a resistor. This current is sourced from a precision current mirror whose output is directed into R_L converting the signal back into a voltage and amplified by the output buffer amplifier. Patent-pending circuit architecture ensures smooth device operation, even during the transition period where both amplifiers A1 and A2 are active.

APPLICATION INFORMATION (continued)

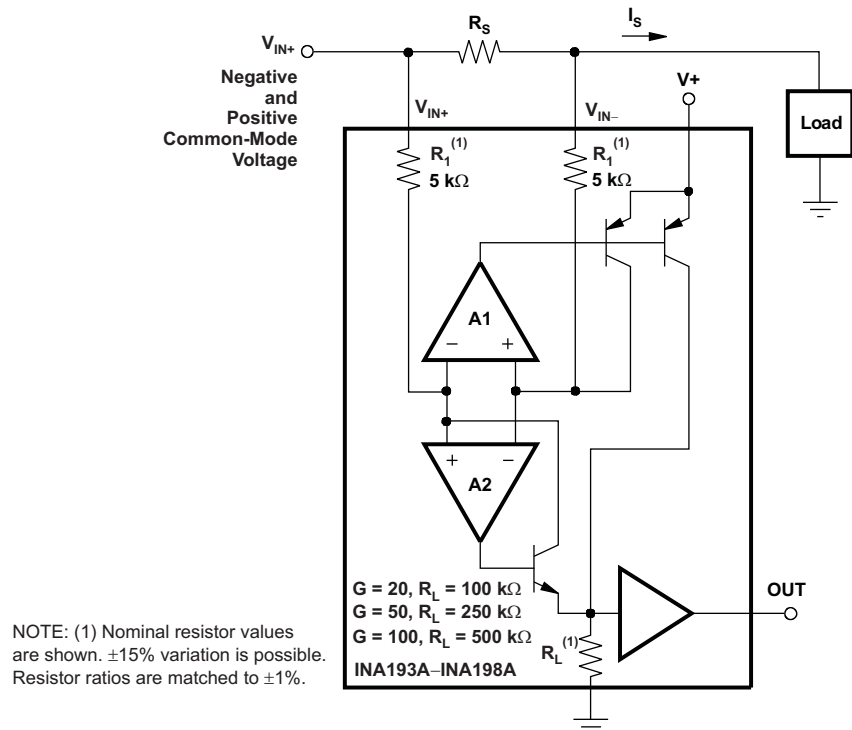


Figure 6. INA193A-INA198A Simplified Circuit Diagram

APPLICATION INFORMATION (continued)

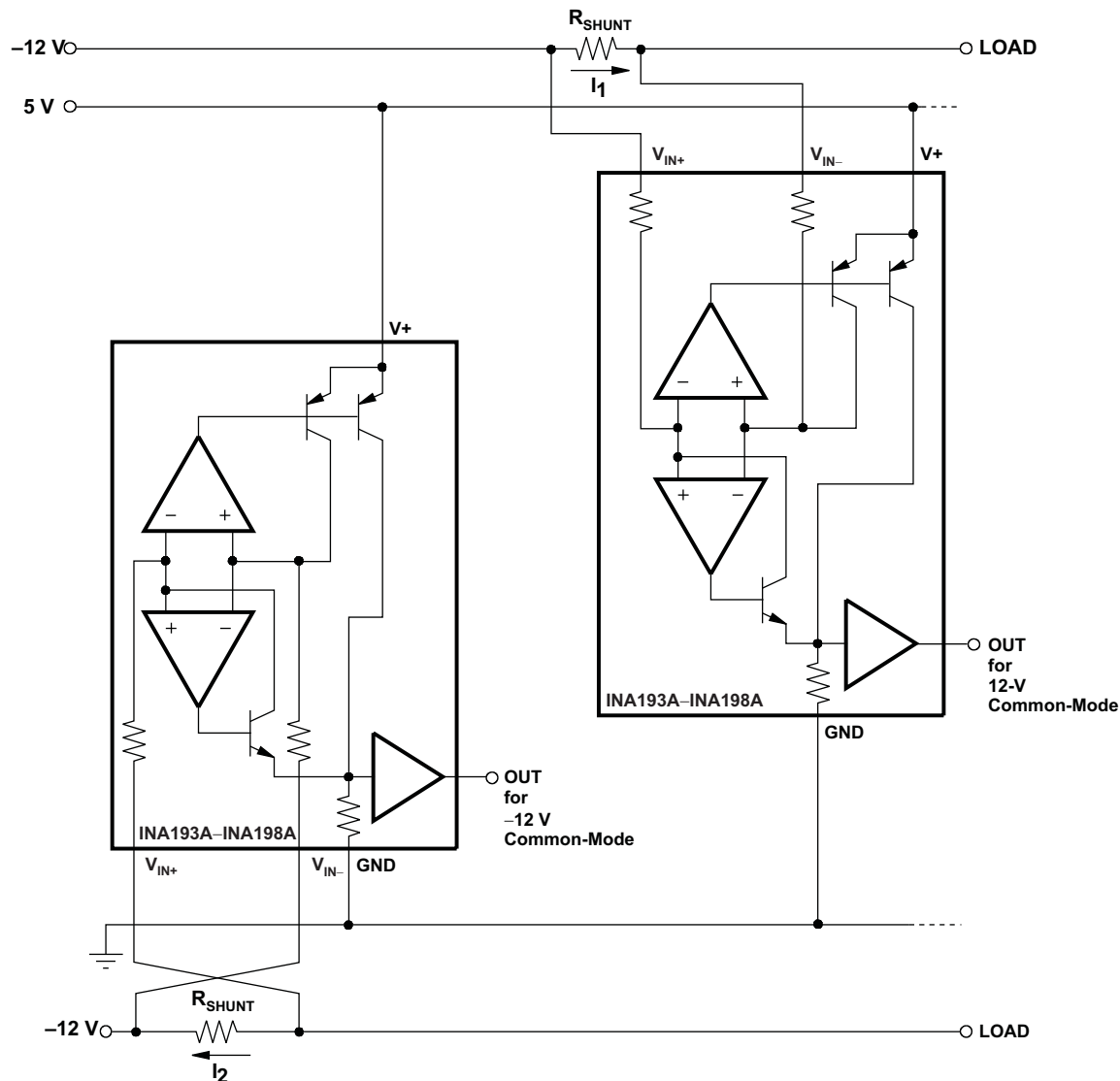


Figure 7. Monitor Bipolar Output Power-Supply Current

APPLICATION INFORMATION (continued)

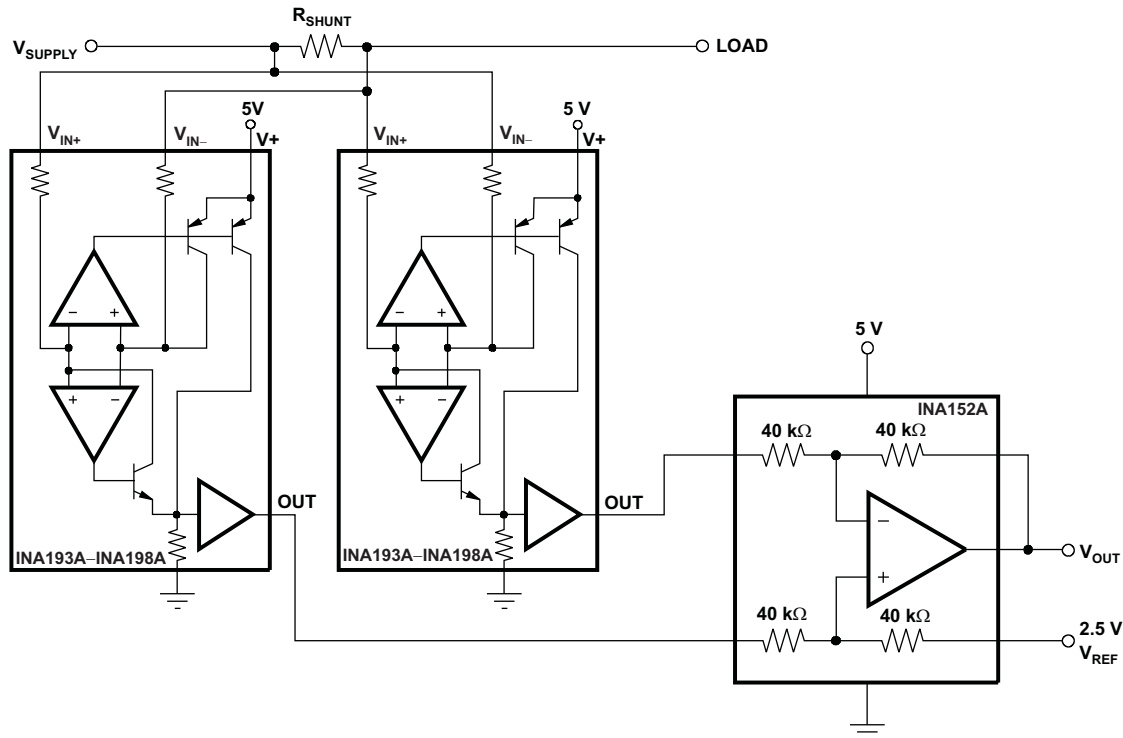


Figure 8. Bidirectional Current Monitoring

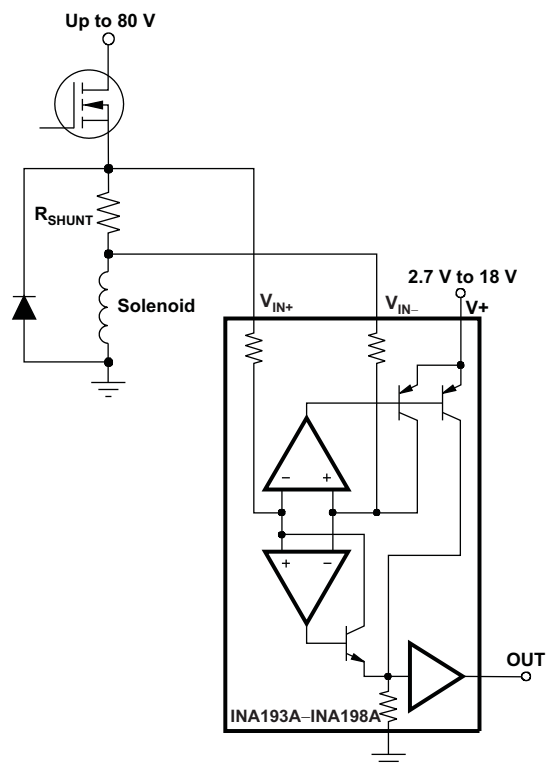


Figure 9. Inductive Current Monitor Including Flyback

APPLICATION INFORMATION (continued)

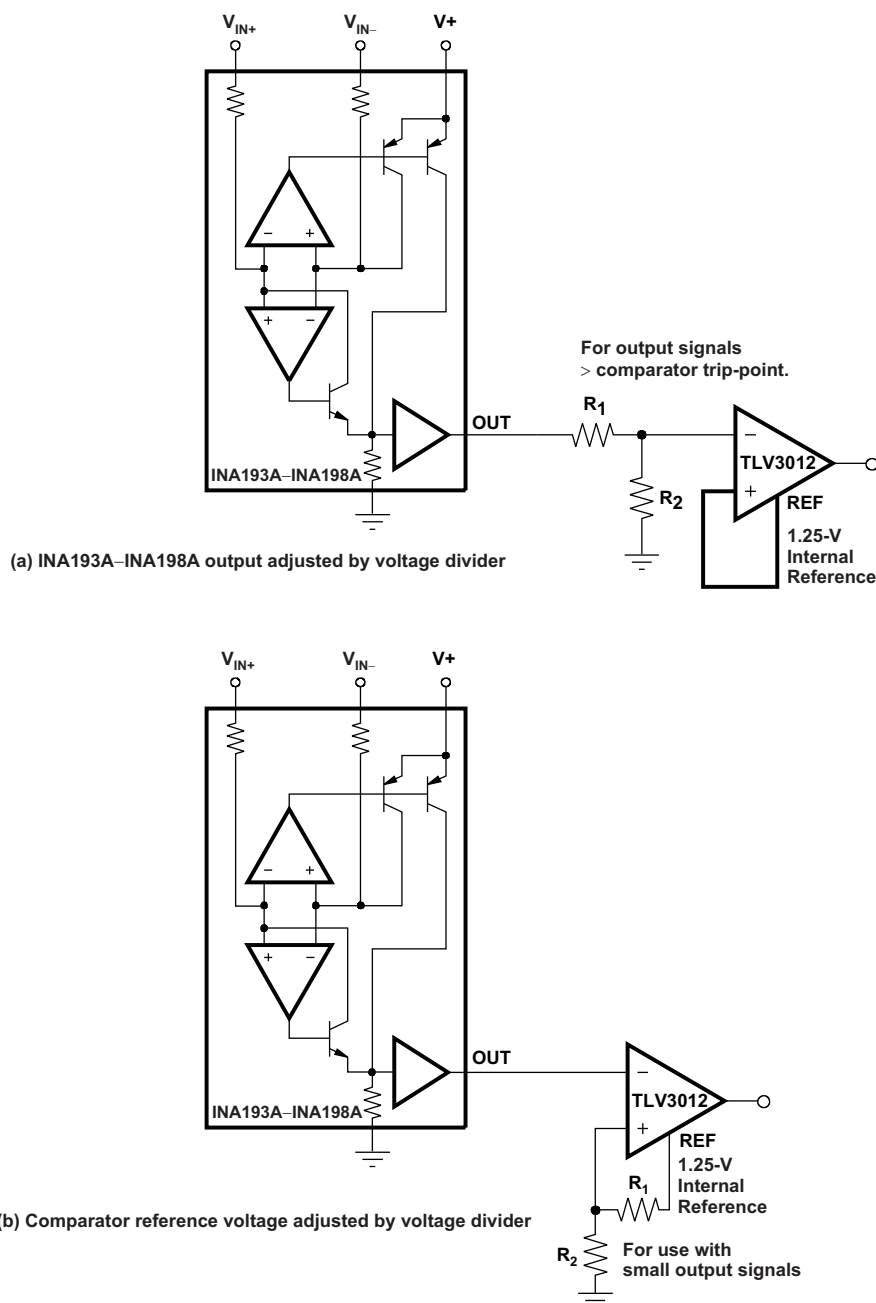


Figure 10. INA193A–INA198A With Comparator

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
INA193AMDBVREP	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
V62/07638-01XE	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

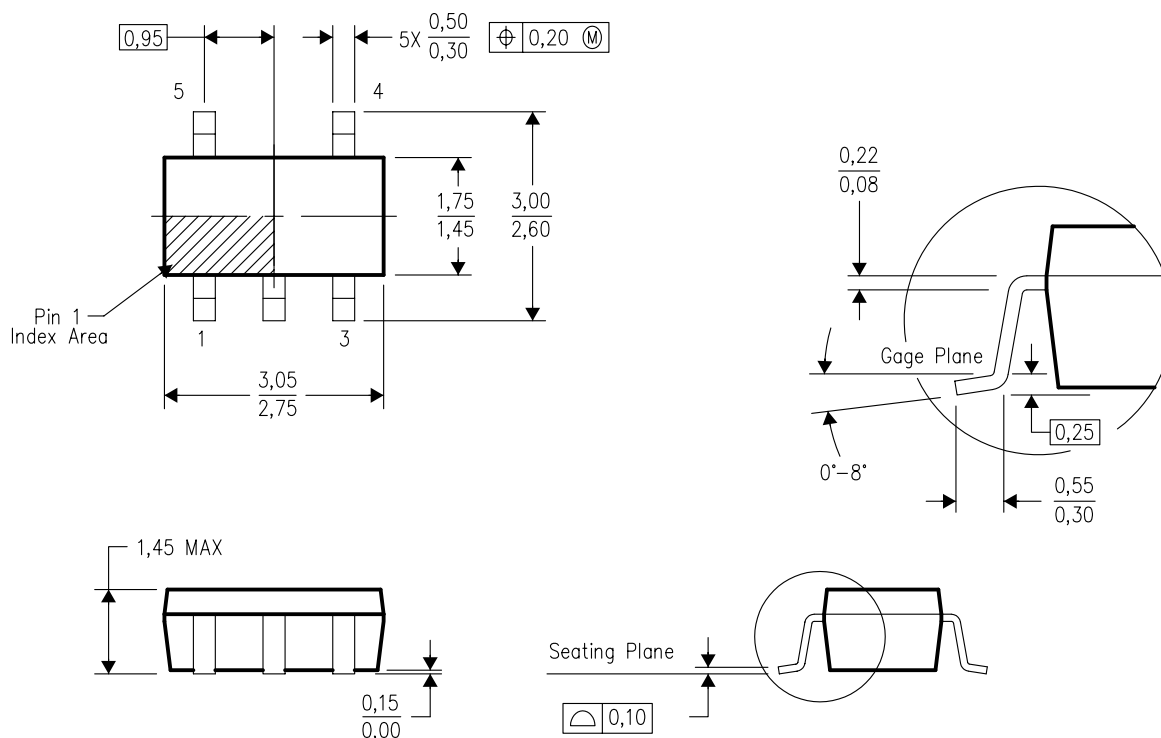
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



4073253-4/K 03/2006

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - Falls within JEDEC MO-178 Variation AA.

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